TOSHIBA

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC273AP,TC74HC273AF

Octal D-Type Flip Flop with Clear

The TC74HC273A is a high speed CMOS OCTAL D-TYPE $\,$

FLIP FLOP fabricated with silicon gate C²MOS technology. It achieves the high speed operation similar to equivalent

LSTTL while maintaining the CMOS low power dissipation.

Information signals applied to D inputs are transferred to the Q outputs on the positive going edge of the clock pulse.

When the $\overline{\text{CLR}}$ input is held "L", the Q outputs are at a low logic level independent of the other inputs.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

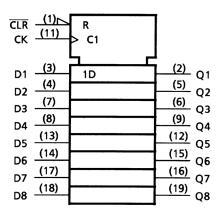
- High speed: $f_{max} = 67 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $Ta = 25^{\circ}C$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: |IOH| = IOL = 4 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2~6 V
- Pin and function compatible with 74LS273

Pin Assignment

CLR Q1 D1	1 2 3	20 19 18	Q8 D8
D2 Q2 Q3	4 5 6 7	17 16 15 15	Q7 Q6
D3 D4 Q4 GND	7 8 9	19 18 17 16 15 14 13 12 12 11	D5 Q5
GND	10	D 11	CK

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IEC Logic Symbol

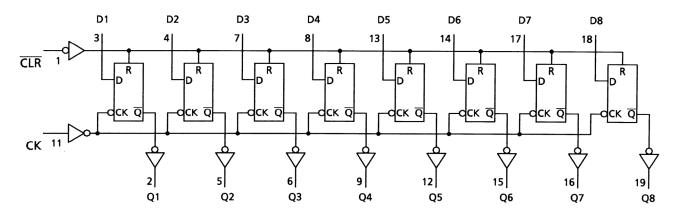


Truth Table

	Inputs		Output	Function
CLR	D	СК	Q	T UNCLION
L	Х	Х	L	Clear
Н	L		L	_
Н	Н		Н	_
Н	Х		Qn	No change

X: Don't care

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input diode current	IIК	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	ICC	±50	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of $Ta = -40 \sim 65^{\circ}$ C. From Ta = 65 to 85° C a derating factor of -10 mW/°C shall be applied until 300 mW.

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2~6	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
		0~1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	$0 \sim 500 \ (V_{CC} = 4.5 \ V)$	ns
		0~400 (V _{CC} = 6.0 V)	

Operating Ranges (Note)

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics Symbol			Test Condition			Ta = 25°C			Ta = -40~85°C	
					Min	Тур.	Max	Min	Max	Unit
				2.0	1.50			1.50	_	
High-level input voltage	VIH		_	4.5	3.15			3.15	—	V
Ŭ				6.0	4.20		_	4.20	_	
				2.0	—		0.50		0.50	
Low-level input voltage	VIL		—	4.5			1.35		1.35	V
Ŭ				6.0			1.80		1.80	
				2.0	1.9	2.0		1.9		
		V _{IN}	I _{OH} = -20 μA	4.5	4.4	4.5	_	4.4	—	
High-level output voltage	V _{OH}	= V _{IH} or		6.0	5.9	6.0	_	5.9	_	V
Ŭ		VIL	$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31		4.13		ν ν ν μΑ
			I _{OH} = -5.2 mA	6.0	5.68	5.80	_	5.63	_	
				2.0	—	0.0	0.1		0.1	
		VIN	I _{OL} = 20 μA	4.5	—	0.0	0.1		0.1	
Low-level output voltage	V _{OL}	= VIH or		6.0		0.0	0.1		0.1	v v
J J		VIL	$I_{OL} = 4 \text{ mA}$	4.5 — 0.17 0.26 —	_	0.33				
			I _{OL} = 5.2 mA	6.0		0.18	0.26		0.33	
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		6.0	—	—	±0.1	_	±1.0	μΑ
Quiescent supply current	ICC	$V_{IN} = V_C$	_C or GND	6.0	_		4.0	_	40.0	μA

Timing Requirements (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Test Condition Ta = 25°C		Ta = _40 ~85°C	Unit	
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	h		2.0	_	75	95	
	t _{W (L)}	—	4.5	—	15	19	ns
(CK)	tw (H)		6.0	—	13	16	
Minimum pulse width			2.0	_	75	95	
	t _{W (L)}	—	4.5	—	15	19	ns
(CLR)			6.0	—	13	16	
			2.0	_	75	95	
Minimum set-up time	t _s	—	4.5	—	15	19	ns
			6.0	_	13	16	
			2.0		0	0	
Minimum hold time	t _h	—	4.5	—	0	0	ns
			6.0	_	0	0	
Minimum removal time			2.0		50	65	
(CLR)	t _{rem}	—	4.5	_	10	13	ns
(CLR)			6.0	_	9	11	
			2.0	_	6	5	
Clock frequency	f	—	4.5	—	30	24	MHz
			6.0	_	35	28	

AC Characteristics ($C_L = 15 \text{ pF}$, $V_{CC} = 5 \text{ V}$, $Ta = 25^{\circ}C$, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition		Тур.	Max	Unit
Output transition time	t _{TLH} t _{THL}	_	_	4	8	ns
Propagation delay time (CK-Q)	t _{pLH} t _{pHL}	_	_	15	25	ns
Propagation delay time (CLR -Q)	^t pLH t _{pHL}	_	_	16	27	ns
Maximum clock frequency	f _{max}	_	40	67		MHz

AC Characteristics ($C_L = 50 \text{ pF}$, input: $t_r = t_f = 6 \text{ ns}$)

		Test Condition		-	Ta = 25°C		Ta = -4		
Characteristics	Symbol		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
Output transition time	tт∟н tтн∟	_	2.0 4.5 6.0		25 7 6	75 15 13		95 19 16	ns
Propagation delay time (CK-Q)	t _{pLH} t _{pHL}		2.0 4.5 6.0		54 18 15	145 29 25		180 36 31	ns
Propagation delay time (CLR -Q)	t _{pLH} t _{pHL}	_	2.0 4.5 6.0	_	60 20 17	160 32 27		200 40 34	ns
Maximum clock frequency	f _{max}	_	2.0 4.5 6.0	6 30 35	18 56 66		5 24 28		MHz
Input capacitance	C _{IN}	_			5	10		10	pF
Power dissipation capacitance	C _{PD} (Note)	_		_	43	—	_	—	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per flip flop)

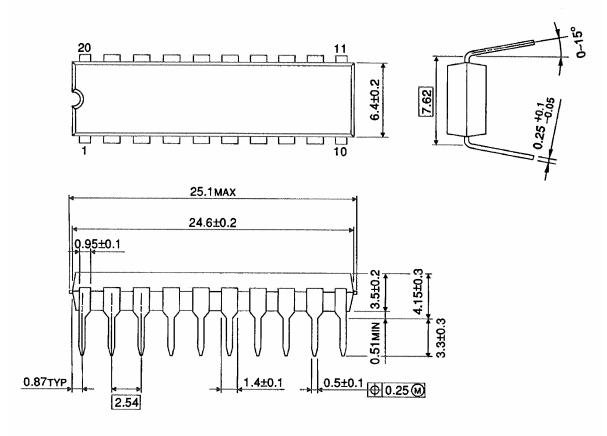
And the total C_{PD} when n pcs. of flip flop operate can be gained by the following equation:

C_{PD} (total) = 32 + 11 · n

Package Dimensions

DIP20-P-300-2.54A

Unit : mm



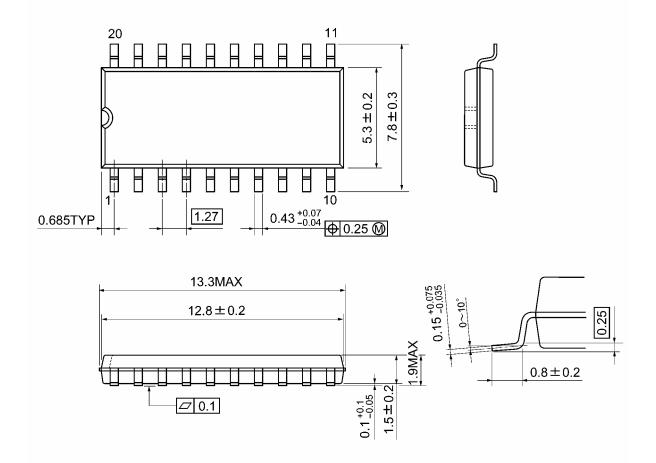
Weight: 1.30 g (typ.)

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Package Dimensions

SOP20-P-300-1.27A

Unit: mm



Weight: 0.22 g (typ.)

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20070701-EN GENERAL

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